

**AZ1117** 

### **General Description**

The AZ1117 is a series of low dropout three-terminal regulators with a dropout of 1.15V at 1A output current.

The AZ1117 series provides current limiting and thermal shutdown. Its circuit includes a trimmed bandgap reference to assure output voltage accuracy to be within 1% for 1.5V, 1.8V, 2.5V, 2.85V, 3.3V, 5.0V and adjustable versions or 2% for 1.2V version. Current limit is trimmed to ensure specified output current and controlled short-circuit current. On-chip thermal shutdown provides protection against any combination of overload and ambient temperature that would create excessive junction temperature.

The AZ1117 has an adjustable version, that can provide the output voltage from 1.25V to 12V with only 2 external resistors.

The AZ1117 series is available in the industry standard SOT-223, SOT-89, TO-220-3, TO-252-2 (1), TO-252-2 (3) and TO-263-3 power packages.

#### **Features**

- Low Dropout Voltage: 1.15V at 1A Output Current
- Trimmed Current Limit
- On-chip Thermal Shutdown
- Three-terminal Adjustable or Fixed 1.2V, 1.5V, 1.8V, 2.5V, 2.85V, 3.3V, 5.0V
- Operation Junction Temperature: -40 to 125°C

### **Applications**

- PC Motherboard
- · LCD Monitor
- Graphic Card
- DVD-video Player
- NIC/Switch
- Telecom Equipment
- ADSL Modem
- Printer and other Peripheral Equipment

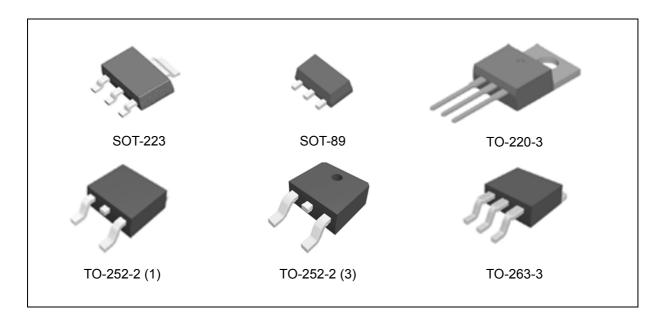


Figure 1. Package Types of AZ1117



## **Pin Configuration**

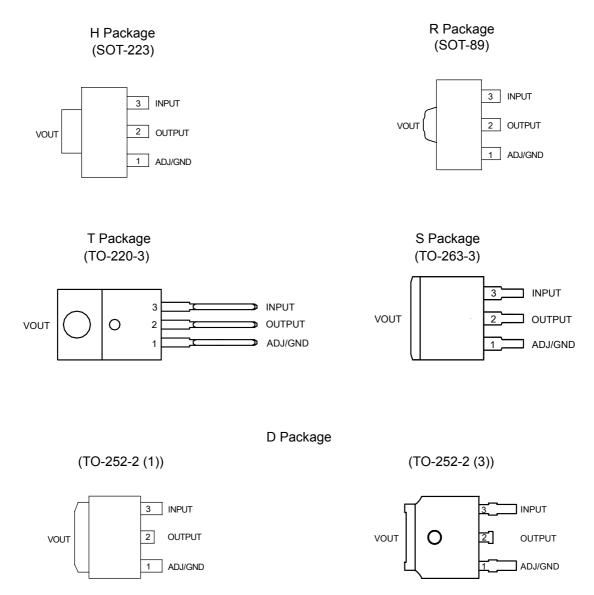


Figure 2. Pin Configuration of AZ1117



## **Functional Block Diagram**

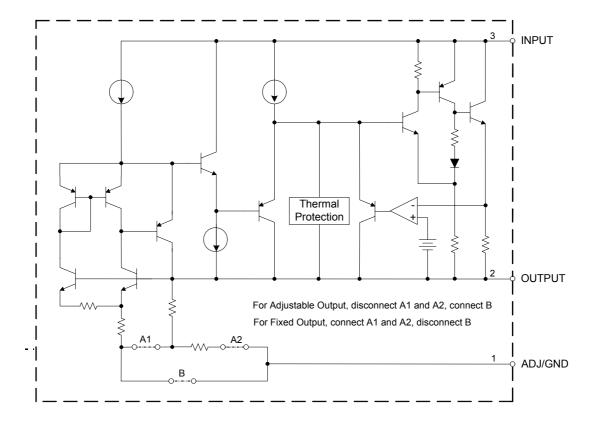
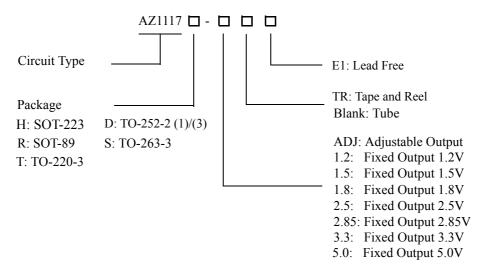


Figure 3. Functional Block Diagram of AZ1117



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## **Ordering Information**



Package	Temperature Range	Part Number	Marking ID	Packing Type
Гаскаде	Temperature Kange	Lead Free	Lead Free	racking Type
		AZ1117H-ADJTRE1	EH11A	Tape & Reel
		AZ1117H-1.2TRE1	EH18A	Tape & Reel
		AZ1117H-1.5TRE1	EH12A	Tape & Reel
SOT-223	40 / 12500	AZ1117H-1.8TRE1	EH13A	Tape & Reel
301-223	-40 to 125°C	AZ1117H-2.5TRE1	EH14A	Tape & Reel
		AZ1117H-2.85TRE1	EH15A	Tape & Reel
		AZ1117H-3.3TRE1	EH16A	Tape & Reel
		AZ1117H-5.0TRE1	EH17A	Tape & Reel
		AZ1117R-ADJTRE1	E17A	Tape & Reel
		AZ1117R-1.2TRE1	E17G	Tape & Reel
		AZ1117R-1.5TRE1	E17B	Tape & Reel
SOT-89	10 / 10 50 G	AZ1117R-1.8TRE1	E17C	Tape & Reel
301-89	-40 to 125°C	AZ1117R-2.5TRE1	E17D	Tape & Reel
		AZ1117R-2.85TRE1	E17H	Tape & Reel
		AZ1117R-3.3TRE1	E17E	Tape & Reel
		AZ1117R-5.0TRE1	E17F	Tape & Reel
		AZ1117T-ADJE1	AZ1117T-ADJE1	Tube
		AZ1117T-1.2E1	AZ1117T-1.2E1	Tube
		AZ1117T-1.5E1	AZ1117T-1.5E1	Tube
TO-220-3	10 - 10 - 10	AZ1117T-1.8E1	AZ1117T-1.8E1	Tube
	-40 to 125°C	AZ1117T-2.5E1	AZ1117T-2.5E1	Tube
		AZ1117T-2.85E1	AZ1117T-2.85E1	Tube
		AZ1117T-3.3E1	AZ1117T-3.3E1	Tube
		AZ1117T-5.0E1	AZ1117T-5.0E1	Tube



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## **Ordering Information (Continued)**

Package	Temperature Range	Part Number	Marking ID	Packing Type
		AZ1117D-ADJE1	AZ1117D-ADJE1	Tube
		AZ1117D-ADJTRE1	AZ1117D-ADJE1	Tape & Reel
		AZ1117D-1.2E1	AZ1117D-1.2E1	Tube
		AZ1117D-1.2TRE1	AZ1117D-1.2E1	Tape & Reel
		AZ1117D-1.5E1	AZ1117D-1.5E1	Tube
		AZ1117D-1.5TRE1	AZ1117D-1.5E1	Tape & Reel
		AZ1117D-1.8E1	AZ1117D-1.8E1	Tube
TO-252-2 (1)/	-40 to 125°C	AZ1117D-1.8TRE1	AZ1117D-1.8E1	Tape & Reel
TO-252-2 (3)		AZ1117D-2.5E1	AZ1117D-2.5E1	Tube
		AZ1117D-2.5TRE1	AZ1117D-2.5E1	Tape & Reel
		AZ1117D-2.85E1	AZ1117D-2.85E1	Tube
		AZ1117D-2.85TRE1	AZ1117D-2.85E1	Tape & Reel
	1 40 to 1259C	AZ1117D-3.3E1	AZ1117D-3.3E1	Tube
		AZ1117D-3.3TRE1	AZ1117D-3.3E1	Tape & Reel
		AZ1117D-5.0E1	AZ1117D-5.0E1	Tube
		AZ1117D-5.0TRE1	AZ1117D-5.0E1	Tape & Reel
		AZ1117S-ADJE1	AZ1117S-ADJE1	Tube
		AZ1117S-ADJTRE1	AZ1117S-ADJE1	Tape & Reel
		AZ1117S-1.2E1	AZ1117S-1.2E1	Tube
		AZ1117S-1.2TRE1	AZ1117S-1.2E1	Tape & Reel
		AZ1117S-1.5E1	AZ1117S-1.5E1	Tube
		AZ1117S-1.5TRE1	AZ1117S-1.5E1	Tape & Reel
		AZ1117S-1.8E1	AZ1117S-1.8E1	Tube
TO-263-3	40 + 1250G	AZ1117S-1.8TRE1	AZ1117S-1.8E1	Tape & Reel
10-203-3	-40 to 125°C	AZ1117S-2.5E1	AZ1117S-2.5E1	Tube
		AZ1117S-2.5TRE1	AZ1117S-2.5E1	Tape & Reel
		AZ1117S-2.85E1	AZ1117S-2.85E1	Tube
		AZ1117S-2.85TRE1	AZ1117S-2.85E1	Tape & Reel
		AZ1117S-3.3E1	AZ1117S-3.3E1	Tube
		AZ1117S-3.3TRE1	AZ1117S-3.3E1	Tape & Reel
		AZ1117S-5.0E1	AZ1117S-5.0E1	Tube
		AZ1117S-5.0TRE1	AZ1117S-5.0E1	Tape & Reel

BCD Semiconductor's Pb-free products, as designated with "E1" suffix in the part number, are RoHS compliant.



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### **Absolute Maximum Ratings (Note 1)**

Parameter	Symbol	Value		Unit
Input Voltage	V <sub>IN</sub>	20		V
Operating Junction Temperature	$T_{\mathrm{J}}$	150		°C
Storage Temperature	$T_S$	-65 to 1	150	°C
Lead Temperature (Soldering, 10sec)	T <sub>LEAD</sub>	260		°C
		SOT-223	120	
		SOT-89	165	
Thermal Resistance (No Heatsink, Note 2)	$\theta_{ m JA}$	TO-220-3	60	°C/W
		TO-252-2 (1)	100	
		TO-252-2 (3)	100	
		TO-263-3	60	
ESD (Human Body Model)	ESD	2000		V
ESD (Machine Model)	ESD	250		V

Note 1: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

Note 2: Absolute maximum ratings indicate limits beyond which damage to the component may occur. Electrical specifications do not apply when operating the device outside of its operating ratings. The maximum allowable power dissipation is a function of the maximum junction temperature,  $T_{J(max)}$ , the junction-to-ambient thermal resistance,  $\theta_{JA}$ , and the ambient temperature,  $T_A$ . The maximum allowable power dissipation at any ambient temperature is calculated using:  $P_{D(max)} = (T_{J(max)} - T_A)/\theta_{JA}$ . Exceeding the maximum allowable power dissipation will result in excessive die temperature, and the regulator will go into thermal shutdown.

#### **Recommended Operating Conditions**

Parameter	Symbol	Min	Max	Unit
Input Voltage	$V_{\rm IN}$		15	V
Operating Junction Temperature Range	$T_{J}$	-40	125	°C



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# **Electrical Characteristics AZ1117-ADJ Electrical Characteristics**

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Reference Voltage	V <sub>REF</sub>	$\begin{split} &I_{OUT}\!=\!10\text{mA}, V_{\text{IN}}\!\!-\!V_{OUT}\!=\!2V\\ &10\text{mA}\!\leq\!I_{OUT}\!\leq\!1\text{A}, 1.4V\!\leq\!V_{\text{IN}}\!\!-\!V_{OUT}\leq\!8V,\\ &P\!\leq\!\text{Maximum Power Dissipation} \end{split}$	1.238 1.225	1.250 1.250	1.262 1.270	V
Line Regulation	$\Delta V_{ m OUT}$	I <sub>OUT</sub> =10mA, 1.5V≤V <sub>IN</sub> -V <sub>OUT</sub> ≤10V		0.035	0.2	%
Load Regulation	$\Delta V_{ m OUT}$	$V_{IN}$ - $V_{OUT}$ =2V, $10$ mA $\leq I_{OUT} \leq 1$ A		0.2	0.4	%
		$\Delta V_{REF}$ =1%, $I_{OUT}$ =0.1A		1.00	1.1	V
Dropout Voltage	$V_{DROP}$	$\Delta V_{REF} = 1\%$ , $I_{OUT} = 0.5A$		1.08	1.18	V
		$\Delta V_{REF}$ =1%, $I_{OUT}$ =1.0A		1.15	1.25	V
Current Limit	I <sub>LIMIT</sub>	V <sub>IN</sub> -V <sub>OUT</sub> =2V	1.25	1.35		Α
Adjust Pin Current	$I_{ADJ}$			60	120	μΑ
Adjust Pin Current Change	$\Delta I_{ ext{ADJ}}$	$1.4\text{V} \leq \text{V}_{\text{IN}} - \text{V}_{\text{OUT}} \leq 10\text{V}, 10\text{mA} \leq \text{I}_{\text{OUT}} \leq 1\text{A}$		0.2	5	μА
Minimum Load Current (ADJ)	I <sub>LOAD</sub> (MIN)	1.5V≤V <sub>IN</sub> -V <sub>OUT</sub> ≤10V (ADJ only)		1.7	5	mA
Quiescent Current	$I_Q$	$V_{IN}=V_{OUT}+1.25V$		5	10	mA
Ripple Rejection	PSRR	f=120Hz, $C_{OUT}$ =22 $\mu$ F Tantalum, $V_{IN}$ - $V_{OUT}$ =3V, $I_{OUT}$ =1A	60	75		dB
Temperature Stability				0.5		%
Long-term Stability		T <sub>A</sub> =125°C, 1000hrs		0.3		%
RMS Output Noise (% of V <sub>OUT</sub> )		T <sub>A</sub> =25°C, 10Hz≤f≤10kHz		0.003		%
Thermal Shutdown		Junction Temperature		150		°C
Thermal Shutdown Hysteresis				25		°C
		SOT-223		25		
		SOT-89		30		
Thermal Resistance	$\theta_{ m JC}$	TO-220-3		10		°C/W
The first testistation	- 10	TO-252-2 (1)		17		°C/W
		TO-252-2 (3)		17		
		TO-263-3		10		



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# **Electrical Characteristics (Continued) AZ1117-1.2 Electrical Characteristics**

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output Voltage	V <sub>OUT</sub>	$ I_{OUT} = 10 \text{mA}, V_{IN} = 3.2 \text{V} $ $ 10 \text{mA} \le I_{OUT} \le 1 \text{A}, 3.0 \text{V} \le V_{IN} \le 10 \text{V} $	1.176 1.152	1.2 1.2	1.224 1.248	V
Line Regulation	$\Delta V_{ m OUT}$	$I_{OUT}$ =10mA, 1.5V $\leq$ V <sub>IN</sub> -V <sub>OUT</sub> $\leq$ 10V		1	6	mV
Load Regulation	$\Delta V_{ m OUT}$	$V_{IN}$ - $V_{OUT}$ =2V, $10$ mA $\leq I_{OUT}\leq 1$ A		1	10	mV
		$\Delta V_{OUT}$ =1%, $I_{OUT}$ =0.1A		1.00	1.1	V
Dropout Voltage	$V_{DROP}$	$\Delta V_{OUT}$ =1%, $I_{OUT}$ =0.5A		1.08	1.18	V
		$\Delta V_{OUT}$ =1%, $I_{OUT}$ =1.0A		1.15	1.25	V
Current Limit	I <sub>LIMIT</sub>	V <sub>IN</sub> -V <sub>OUT</sub> =2V	1.25	1.35		A
Quiescent Current	$I_Q$	V <sub>IN</sub> =V <sub>OUT</sub> +1.25V		5	10	mA
Ripple Rejection	PSRR	$f$ =120Hz, $C_{OUT}$ =22 $\mu$ F Tantalum, $V_{IN}$ - $V_{OUT}$ =3 $V$ , $I_{OUT}$ =1 $A$	60	75		dB
Temperature Stability				0.5		%
Long-term Stability		T <sub>A</sub> =125°C, 1000hrs		0.3		%
RMS Output Noise (% of V <sub>OUT</sub> )		T <sub>A</sub> =25°C, 10Hz≤ f≤10kHz		0.003		%
Thermal Shutdown		Junction Temperature		150		°C
Thermal Shutdown Hysteresis				25		°C
		SOT-223		25		
		SOT-89		30		
Thermal Resistance	$\theta_{ m JC}$	TO-220-3		10		00.777
Thermal Resistance	ojc	TO-252-2 (1)		17		°C/W
		TO-252-2 (3)		17		
		TO-263-3		10		



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## **Electrical Characteristics (Continued) AZ1117-1.5 Electrical Characteristics**

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output Voltage	V <sub>OUT</sub>	$I_{OUT}$ =10mA, $V_{IN}$ =3.5V 10mA $\leq I_{OUT} \leq$ 1A, 3.0V $\leq V_{IN} \leq$ 10V	1.485 1.470	1.5 1.5	1.515 1.530	V
Line Regulation	$\Delta V_{ m OUT}$	$I_{OUT}=10 \text{mA}, 1.5 \text{V} \le V_{IN}-V_{OUT} \le 10 \text{V}$		1	6	mV
Load Regulation	$\Delta V_{OUT}$	$V_{\text{IN}}$ - $V_{\text{OUT}}$ =2V, $10\text{mA} \le I_{\text{OUT}} \le 1\text{A}$		1	10	mV
		ΔV <sub>OUT</sub> =1%, I <sub>OUT</sub> =0.1A		1.00	1.1	V
Dropout Voltage	$V_{DROP}$	ΔV <sub>OUT</sub> =1%, I <sub>OUT</sub> =0.5A		1.08	1.18	V
		$\Delta V_{OUT}$ =1%, $I_{OUT}$ =1.0A		1.15	1.25	V
Current Limit	I <sub>LIMIT</sub>	V <sub>IN</sub> -V <sub>OUT</sub> =2V	1.25	1.35		A
Quiescent Current	$I_Q$	V <sub>IN</sub> =V <sub>OUT</sub> +1.25V		5	10	mA
Ripple Rejection	PSRR	f=120Hz, $C_{OUT}$ =22 $\mu$ F Tantalum, $V_{IN}$ - $V_{OUT}$ =3V, $I_{OUT}$ =1A	60	75		dB
Temperature Stability				0.5		%
Long-term Stability		T <sub>A</sub> =125°C, 1000hrs		0.3		%
RMS Output Noise (% of V <sub>OUT</sub> )		T <sub>A</sub> =25°C, 10Hz≤f≤10kHz		0.003		%
Thermal Shutdown		Junction Temperature		150		°C
Thermal Shutdown Hysteresis				25		°С
		SOT-223		25		
		SOT-89		30		
	Α	TO-220-3		10		°C/W
Thermal Resistance	$\theta_{ m JC}$	TO-252-2 (1)		17		
		TO-252-2 (3)		17		
		TO-263-3		10		



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## **Electrical Characteristics (Continued) AZ1117-1.8 Electrical Characteristics**

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output Voltage	V <sub>OUT</sub>	$I_{OUT}$ =10mA, $V_{IN}$ =3.8V 10mA≤ $I_{OUT}$ ≤1A, 3.2V≤ $V_{IN}$ ≤10V	1.782 1.746	1.8 1.8	1.818 1.854	V
Line Regulation	$\Delta V_{ m OUT}$	I <sub>OUT</sub> =10mA, 1.5V≤V <sub>IN</sub> -V <sub>OUT</sub> ≤10V		1	6	mV
Load Regulation	$\Delta V_{ m OUT}$	$V_{IN}$ - $V_{OUT}$ =2 $V$ , $10$ m $A \le I_{OUT} \le 1$ A		1	10	mV
		$\Delta V_{OUT}$ =1%, $I_{OUT}$ =0.1A		1.00	1.1	V
Dropout Voltage	$V_{DROP}$	ΔV <sub>OUT</sub> =1%, I <sub>OUT</sub> =0.5A		1.08	1.18	V
		ΔV <sub>OUT</sub> =1%, I <sub>OUT</sub> =1.0A		1.15	1.25	V
Current Limit	I <sub>LIMIT</sub>	V <sub>IN</sub> -V <sub>OUT</sub> =2V	1.25	1.35		A
Quiescent Current	$I_Q$	V <sub>IN</sub> =V <sub>OUT</sub> +1.25V		5	10	mA
Ripple Rejection	PSRR	f=120Hz, C <sub>OUT</sub> =22μF Tantalum, V <sub>IN</sub> -V <sub>OUT</sub> =3V, I <sub>OUT</sub> =1A	60	75		dB
Temperature Stability				0.5		%
Long-term Stability		T <sub>A</sub> =125°C, 1000hrs		0.3		%
RMS Output Noise (% of V <sub>OUT</sub> )		$T_A=25^{\circ}C, 10Hz \le f \le 10kHz$		0.003		%
Thermal Shutdown		Junction Temperature		150		°С
Thermal Shutdown Hysteresis				25		°C
		SOT-223		25		
		SOT-89		30		
	$\theta_{ m JC}$	TO-220-3		10		°C/W
Thermal Resistance	JC	TO-252-2 (1)		17		
		TO-252-2 (3)		17		
		TO-263-3		10		



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## **Electrical Characteristics (Continued) AZ1117-2.5 Electrical Characteristics**

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output Voltage	V <sub>OUT</sub>	$I_{OUT}$ =10mA, $V_{IN}$ =4.5V 10mA≤ $I_{OUT}$ ≤1A, 3.9V≤ $V_{IN}$ ≤10V	2.475 2.450	2.5 2.5	2.525 2.550	V
Line Regulation	$\Delta V_{ m OUT}$	I <sub>OUT</sub> =10mA, 1.5V≤V <sub>IN</sub> -V <sub>OUT</sub> ≤10V		1	6	mV
Load Regulation	$\Delta V_{OUT}$	$V_{\text{IN}}$ - $V_{\text{OUT}}$ = 2V, $10\text{mA} \le I_{\text{OUT}} \le 1\text{A}$		1	10	mV
		ΔV <sub>OUT</sub> =1%, I <sub>OUT</sub> =0.1A		1.00	1.1	V
Dropout Voltage	$V_{DROP}$	ΔV <sub>OUT</sub> =1%, I <sub>OUT</sub> =0.5A		1.08	1.18	V
		ΔV <sub>OUT</sub> =1%, I <sub>OUT</sub> =1.0A		1.15	1.25	V
Current Limit	I <sub>LIMIT</sub>	V <sub>IN</sub> -V <sub>OUT</sub> =2V	1.25	1.35		A
Quiescent Current	$I_Q$	V <sub>IN</sub> =V <sub>OUT</sub> +1.25V		5	10	mA
Ripple Rejection	PSRR	$\begin{split} f = &120 Hz,  C_{OUT} = &22 \mu F  Tantalum, \\ &V_{IN} - &V_{OUT} = &3 V,  I_{OUT} = &1 A \end{split}$	60	75		dB
Temperature Stability				0.5		%
Long-term Stability		T <sub>A</sub> =125°C, 1000hrs		0.3		%
RMS Output Noise (% of V <sub>OUT</sub> )		T <sub>A</sub> =25°C, 10Hz≤f≤10kHz		0.003		%
Thermal Shutdown		Junction Temperature		150		°C
Thermal Shutdown Hysteresis				25		°С
		SOT-223		25		
		SOT-89		30		
Thermal Desigtones	Α	TO-220-3		10		°C/W
Thermal Resistance	$\theta_{ m JC}$	TO-252-2 (1)		17		
		TO-252-2 (3)		17		
		TO-263-3	,	10		



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## **Electrical Characteristics (Continued) AZ1117-2.85 Electrical Characteristics**

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output Voltage	V <sub>OUT</sub>	$I_{OUT}=10\text{mA}, V_{IN}=4.85V$ $10\text{mA} \le I_{OUT} \le 1\text{A}, 4.25V \le V_{IN} \le 10V$	2.822 2.793	2.85 2.85	2.878 2.907	V
Line Regulation	$\Delta V_{ m OUT}$	I <sub>OUT</sub> =10mA, 1.5V≤V <sub>IN</sub> -V <sub>OUT</sub> ≤10V		1	6	mV
Load Regulation	$\Delta V_{ m OUT}$	$V_{IN}$ - $V_{OUT}$ =2V, $10$ mA $\leq I_{OUT}\leq 1$ A		1	10	mV
Dropout Voltage		$\Delta V_{REF}=1\%$ , $I_{OUT}=0.1A$		1.00	1.1	V
	V <sub>DROP</sub>	$\Delta V_{REF}=1\%$ , $I_{OUT}=0.5A$		1.08	1.18	V
		$\Delta V_{REF}$ =1%, $I_{OUT}$ =1.0A		1.15	1.25	V
Current Limit	I <sub>LIMIT</sub>	V <sub>IN</sub> -V <sub>OUT</sub> =2V	1.25	1.35		A
Quiescent Current	$I_Q$	$V_{IN}=V_{OUT}+1.25V$		5	10	mA
Ripple Rejection	PSRR	$f$ =120Hz, $C_{OUT}$ =22 $\mu$ F Tantalum, $V_{IN}$ - $V_{OUT}$ =3 $V$ , $I_{OUT}$ =1 $A$	60	75		dB
Temperature Stability				0.5		%
Long-term Stability		T <sub>A</sub> =125°C, 1000hrs		0.3		%
RMS Output Noise (% of V <sub>OUT</sub> )		T <sub>A</sub> =25°C, 10Hz≤f≤10kHz		0.003		%
Thermal Shutdown		Junction Temperature		150		°С
Thermal Shutdown Hysteresis				25		°С
		SOT-223		25		
		SOT-89		30		
TI 10 11		TO-220-3		10		°C/W
Thermal Resistance	$\theta_{ m JC}$	TO-252-2 (1)		17		
		TO-252-2 (3)		17		
		TO-263-3		10		



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## **Electrical Characteristics (Continued) AZ1117-3.3 Electrical Characteristics**

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output Voltage	V <sub>OUT</sub>	$I_{OUT}$ =10mA, $V_{IN}$ =5.0V 10mA≤ $I_{OUT}$ ≤1A, 4.75V≤ $V_{IN}$ ≤10V	3.267 3.235	3.3 3.3	3.333 3.365	V
Line Regulation	$\Delta V_{OUT}$	I <sub>OUT</sub> =10mA, 1.5V≤V <sub>IN</sub> -V <sub>OUT</sub> ≤10V		1	6	mV
Load Regulation	$\Delta V_{ m OUT}$	$V_{IN}$ - $V_{OUT}$ =2 $V$ , $10mA \le I_{OUT} \le 1A$		1	10	mV
Dropout Voltage		$\Delta V_{OUT}$ =1%, $I_{OUT}$ =0.1A		1.00	1.1	V
	$V_{DROP}$	ΔV <sub>OUT</sub> =1%, I <sub>OUT</sub> =0.5A		1.08	1.18	V
		ΔV <sub>OUT</sub> =1%, I <sub>OUT</sub> =1.0A		1.15	1.25	V
Current Limit	I <sub>LIMIT</sub>	V <sub>IN</sub> -V <sub>OUT</sub> =2V	1.25	1.35		A
Quiescent Current	$I_Q$	V <sub>IN</sub> =V <sub>OUT</sub> +1.25V		5	10	mA
Ripple Rejection	PSRR	f=120Hz, $C_{OUT}$ =22 $\mu$ F Tantalum, $V_{IN}$ - $V_{OUT}$ =3V, $I_{OUT}$ =1A	60	75		dB
Temperature Stability				0.5		%
Long-term Stability		T <sub>A</sub> =125°C, 1000hrs		0.3		%
RMS Output Noise (% of V <sub>OUT</sub> )		T <sub>A</sub> =25°C, 10Hz≤f≤10kHz		0.003		%
Thermal Shutdown		Junction Temperature		150		°С
Thermal Shutdown Hysteresis				25		°C
		SOT-223		25		
		SOT-89		30		
TI ID:	$\theta_{ m JC}$	TO-220-3		10		°C/W
Thermal Resistance	ojc	TO-252-2 (1)		17		
		TO-252-2 (3)		17		
		TO-263-3		10		



**AZ1117** 

## **Electrical Characteristics (Continued) AZ1117-5.0 Electrical Characteristics**

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output Voltage	V <sub>OUT</sub>	$I_{OUT}$ =10mA, $V_{IN}$ =7.0V 10mA $\leq I_{OUT}\leq$ 1A, 6.5V $\leq V_{IN}\leq$ 12V	4.950 4.900	5.0 5.0	5.050 5.100	V
Line Regulation	$\Delta V_{ m OUT}$	I <sub>OUT</sub> =10mA, 1.5V≤V <sub>IN</sub> -V <sub>OUT</sub> ≤10V		1	10	mV
Load Regulation	$\Delta V_{ m OUT}$	$V_{IN}$ - $V_{OUT}$ =2V, $10$ mA $\leq I_{OUT}\leq 1$ A		1	15	mV
		$\Delta V_{OUT}=1\%$ , $I_{OUT}=0.1A$		1.00	1.1	V
Dropout Voltage	$V_{DROP}$	ΔV <sub>OUT</sub> =1%, I <sub>OUT</sub> =0.5A		1.08	1.18	V
		ΔV <sub>OUT</sub> =1%, I <sub>OUT</sub> =1.0A		1.15	1.25	V
Current Limit	I <sub>LIMIT</sub>	V <sub>IN</sub> -V <sub>OUT</sub> =2V	1.25	1.35		A
Quiescent Current	$I_Q$	V <sub>IN</sub> =V <sub>OUT</sub> +1.25V		5	10	mA
Ripple Rejection	PSRR	$\begin{split} f = &120 \text{Hz, } C_{OUT} = &22 \mu \text{F Tantalum,} \\ V_{IN} - &V_{OUT} = &3 \text{V, } I_{OUT} = &1 \text{A} \end{split}$	60	75		dB
Temperature Stability				0.5		%
Long-term Stability		T <sub>A</sub> =125°C, 1000hrs		0.3		%
RMS Output Noise (% of V <sub>OUT</sub> )		T <sub>A</sub> =25°C, 10Hz≤f≤10kHz		0.003		%
Thermal Shutdown		Junction Temperature		150		°С
Thermal Shutdown Hysteresis				25		°C
		SOT-223		25		
		SOT-89		30		
	$\theta_{ m JC}$	TO-220-3		10		0.0.77
Thermal Resistance	JC	TO-252-2 (1)		17		°C/W
		TO-252-2 (3)		17		
		TO-263-3		10		



### **Typical Performance Characteristics**

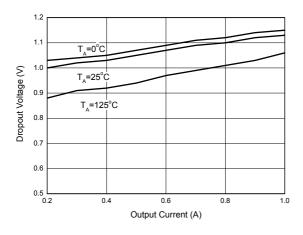
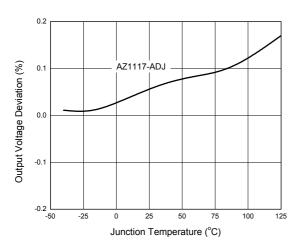


Figure 4. Dropout Voltage vs. Output Current

Figure 5. Dropout Voltage vs. Junction Temperature



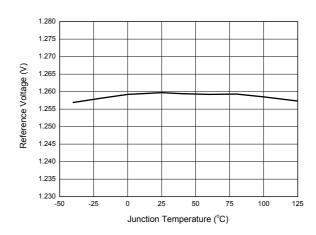
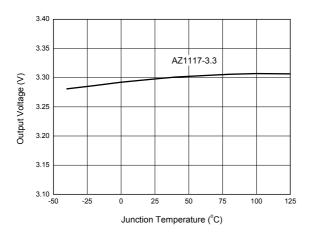


Figure 6. Load Regulation vs. Junction Temperature

Figure 7. Reference Voltage vs. Junction Temperature



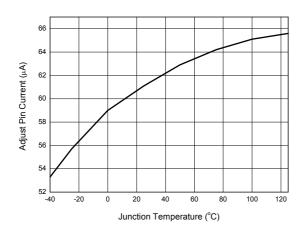
## **Typical Performance Characteristics (Continued)**



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Figure 8. Output Voltage vs. Junction Temperature

Figure 9. Minimum Load Current vs. Junction Temperature



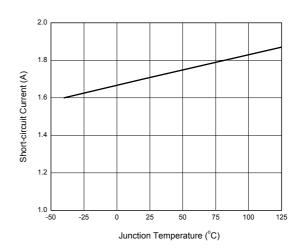


Figure 10. Adjust Pin Current vs. Junction Temperature

Figure 11. Short-circuit Current vs. Junction Temperature



## **Typical Performance Characteristics (Continued)**

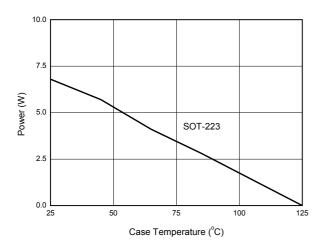
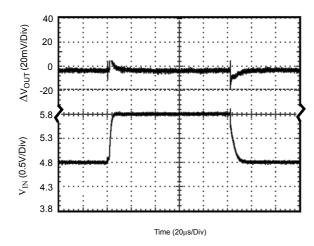
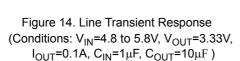


Figure 12. Maximum Power Dissipation

Figure 13. Ripple Rejection vs. Frequency





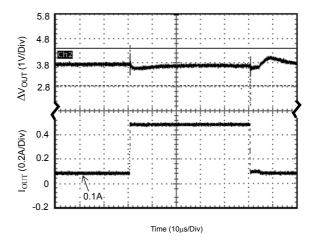
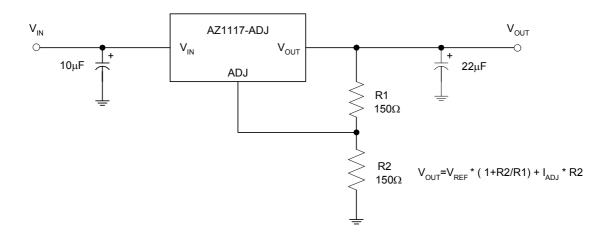


Figure 15. Load Transient Response (Conditions:  $V_{IN}$ =4.8V,  $V_{OUT}$ =3.33V,  $I_{OUT}$ =0.1 to 0.5A,  $C_{IN}$ = $C_{OUT}$ =10 $\mu$ F)



## **Typical Applications**



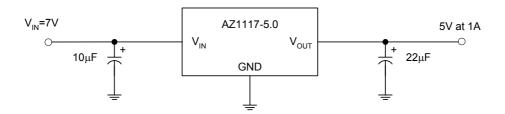
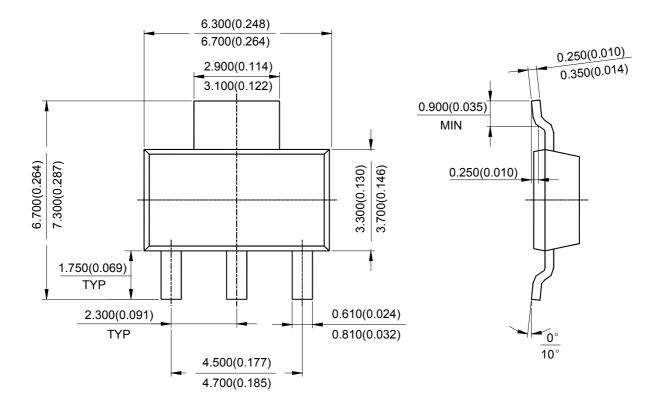


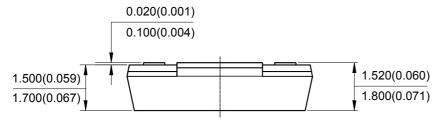
Figure 16. Typical Applications of AZ1117



#### **Mechanical Dimensions**

SOT-223 Unit: mm(inch)

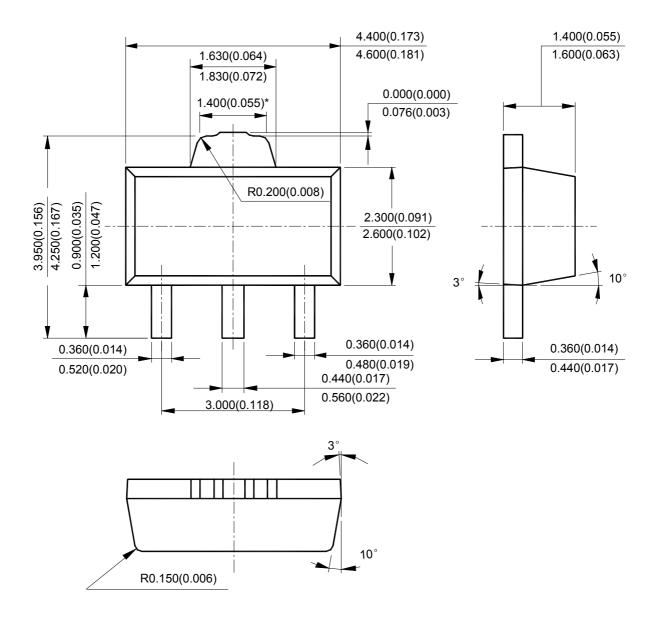






## **Mechanical Dimensions (Continued)**

SOT-89 Unit: mm(inch)



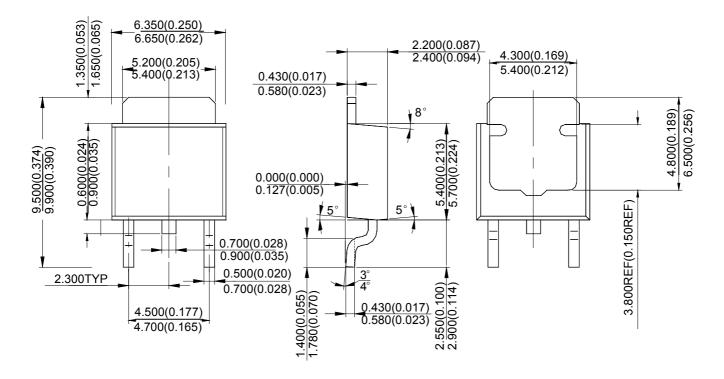


**AZ1117** 

Unit: mm(inch)

### **Mechanical Dimensions (Continued)**

TO-252-2 (1)



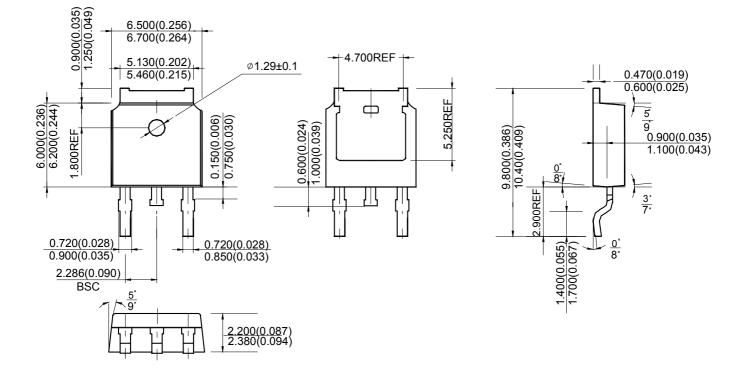


**AZ1117** 

## **Mechanical Dimensions (Continued)**

TO-252-2 (3)

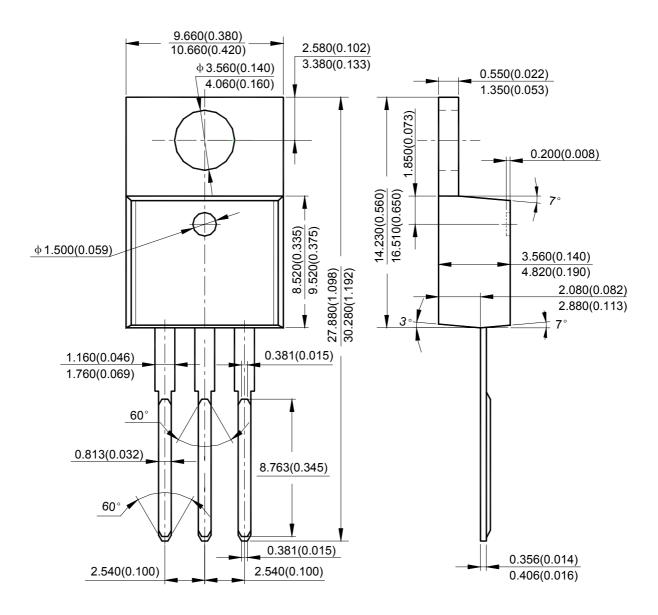
Unit: mm(inch)



**AZ1117** 

### **Mechanical Dimensions (Continued)**

TO-220-3 Unit: mm(inch)

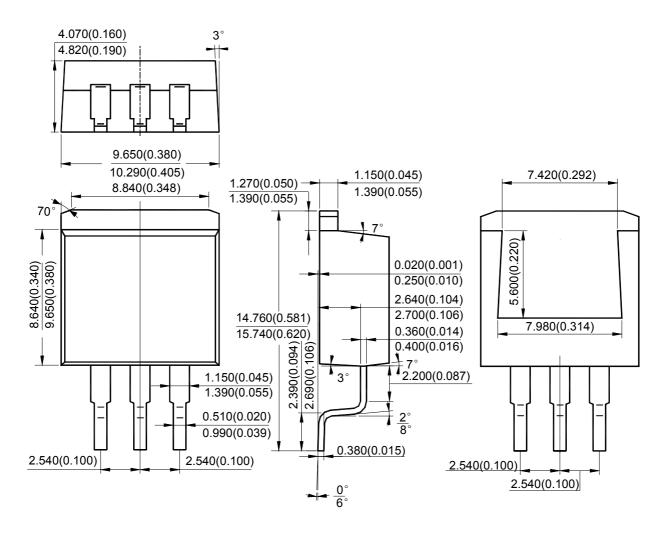




**AZ1117** 

### **Mechanical Dimensions (Continued)**

TO-263-3 Unit: mm(inch)







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